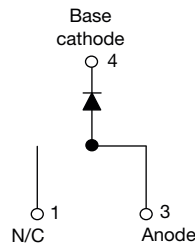


## Hyperfast Rectifier, 20 A FRED Pt® G5


**D²PAK 2L (TO-263AB 2L)**


### FEATURES

- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
 COMPLIANT  
 HALOGEN  
**FREE**

### LINKS TO ADDITIONAL RESOURCES



3D Models

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	20 A
$V_R$	600 V
$V_F$ at $I_F$ at 125 °C	1.40 V
$t_{rr}$ (typ.)	19 ns
$T_J$ max.	175 °C
Package	D²PAK 2L (TO-263AB 2L)
Circuit configuration	Single

### DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications

### MECHANICAL DATA

**Case:** D²PAK 2L (TO-263AB 2L)

Molding compound meets UL 94 V-0 flammability rating

**Terminals:** matte tin plated leads, solderable per J-STD-002

### ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Repetitive peak reverse voltage	$V_{RRM}$		600	V
Average rectified forward current	$I_{F(AV)}$	$T_C = 107\text{ °C}$ , $D = 0.50$	20	A
Repetitive peak forward current	$I_{FRM}$	$T_C = 107\text{ °C}$ , $D = 0.50$ , $f = 20\text{ kHz}$	40	
Non-repetitive peak surge current	$I_{FSM}$	$T_C = 25\text{ °C}$ , $t_p = 10\text{ ms}$ , sine wave	185	
Operating junction and storage temperature	$T_J$ , $T_{Stg}$		-55 to +175	°C

### ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}$ , $V_R$	$I_R = 100\text{ }\mu\text{A}$	600	-	-	V
Forward voltage	$V_F$	$I_F = 20\text{ A}$	-	1.7	2.31	
		$I_F = 20\text{ A}$ , $T_J = 125\text{ °C}$	-	1.40	-	
Reverse leakage current	$I_R$	$V_R = V_R$ rated	-	-	10	$\mu\text{A}$
		$T_J = 125\text{ °C}$ , $V_R = V_R$ rated	-	-	500	
Junction capacitance	$C_T$	$V_R = 200\text{ V}$	-	25	-	pF
Series inductance	$L_S$	Measured to lead 5 mm from package body	-	8	-	nH



<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1.0\text{ A}, di_F/dt = 100\text{ A}/\mu\text{s}, V_R = 30\text{ V}$		-	19	-	ns
		$T_J = 25\text{ }^\circ\text{C}$	$I_F = 12\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	-	33	-	
		$T_J = 125\text{ }^\circ\text{C}$		-	43	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^\circ\text{C}$	$I_F = 12\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	-	12	-	A
		$T_J = 125\text{ }^\circ\text{C}$		-	20	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	$I_F = 12\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	-	185	-	nC
		$T_J = 125\text{ }^\circ\text{C}$		-	510	-	
Reverse recovery time	$t_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	$I_F = 20\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	-	41	-	ns
		$T_J = 125\text{ }^\circ\text{C}$		-	50	-	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^\circ\text{C}$	$I_F = 20\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	-	12	-	A
		$T_J = 125\text{ }^\circ\text{C}$		-	19	-	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	$I_F = 20\text{ A}$ $di_F/dt = 1000\text{ A}/\mu\text{s}$ $V_R = 400\text{ V}$	-	240	-	nC
		$T_J = 125\text{ }^\circ\text{C}$		-	640	-	

<b>THERMAL - MECHANICAL SPECIFICATIONS</b>						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	$R_{thJC}$		-	-	1.72	$^\circ\text{C}/\text{W}$
Weight			-	2.0	-	g
			-	0.07	-	oz.
Maximum junction and storage temperature range	$T_J, T_{Stg}$		-55	-	175	$^\circ\text{C}$
Marking device		Case style D <sup>2</sup> PAK 2L (TO-263AB 2L)	E5TX2106SH			

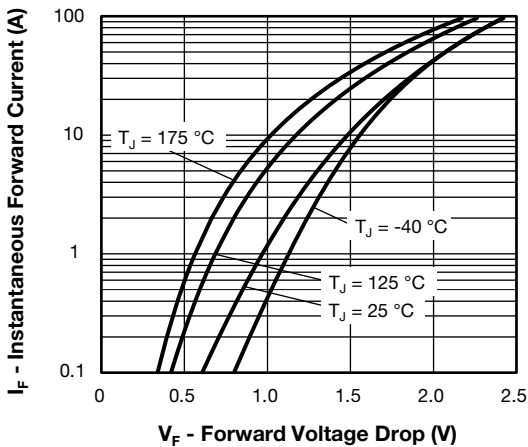


Fig. 1 - Forward Voltage Drop Characteristics

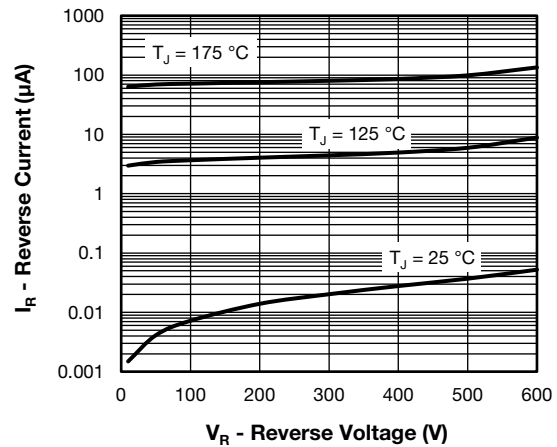


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

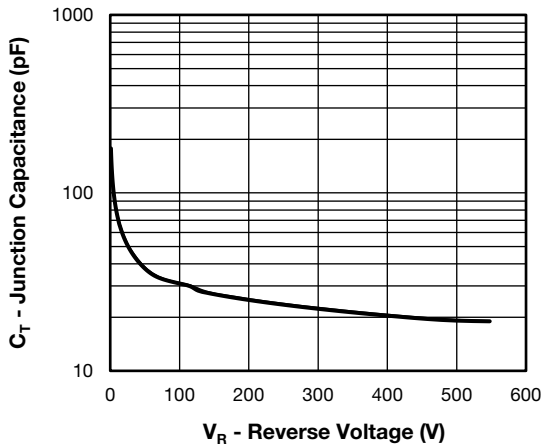


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

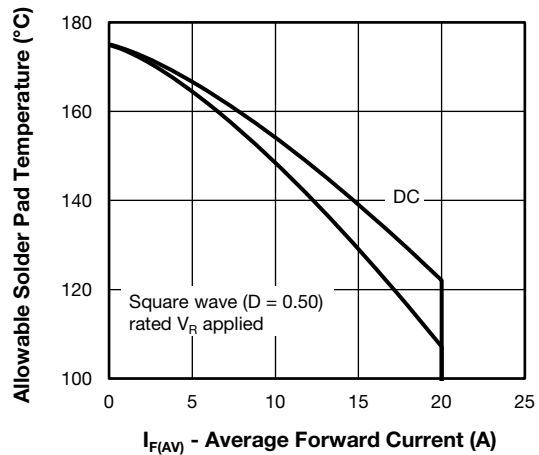


Fig. 4 - Maximum Allowable Case Temperature vs. Average Forward Current

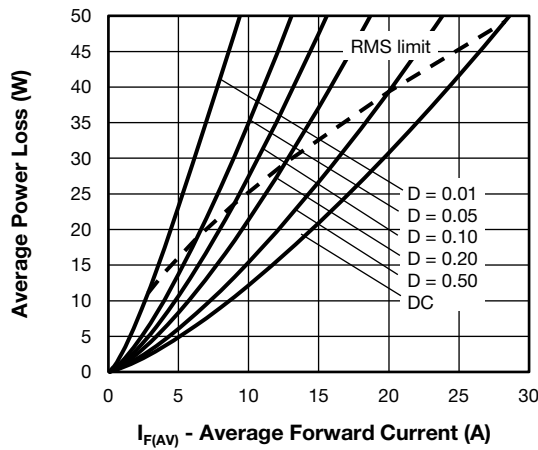


Fig. 5 - Forward Power Loss Characteristics

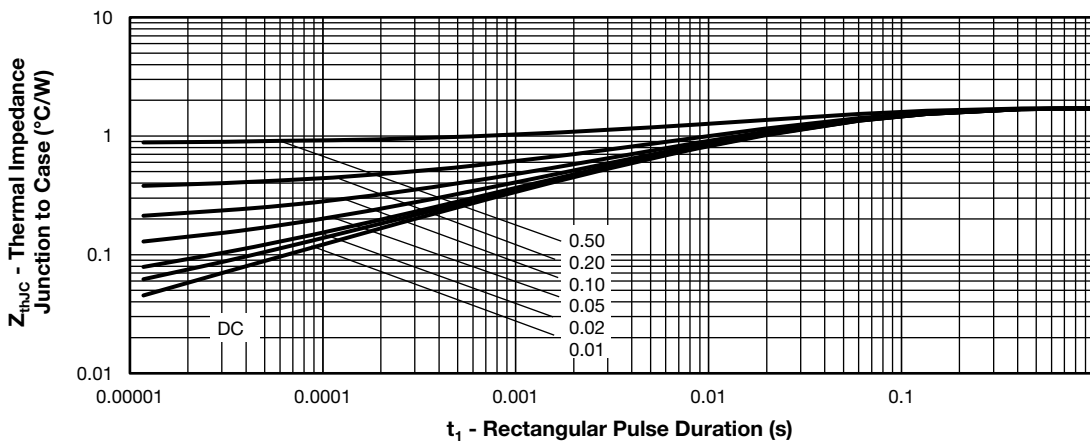


Fig. 6 - Transient Thermal Impedance, Junction to Case

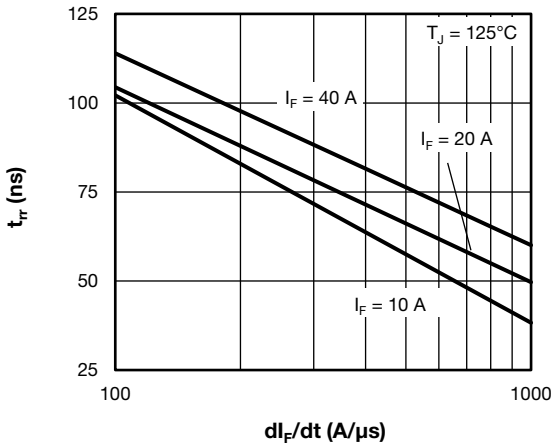


Fig. 7 - Typical Reverse Recovery Time vs.  $di_F/dt$

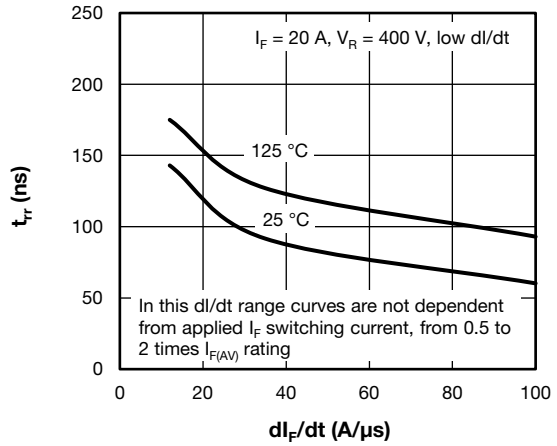


Fig. 10 - Typical Reverse Recovery Time vs.  $di_F/dt$

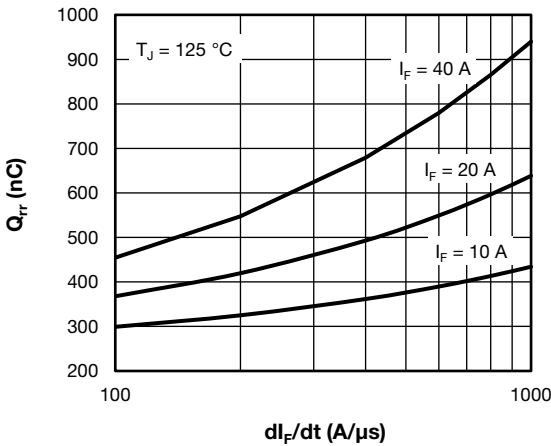


Fig. 8 - Typical Reverse Recovery Charge vs.  $di_F/dt$

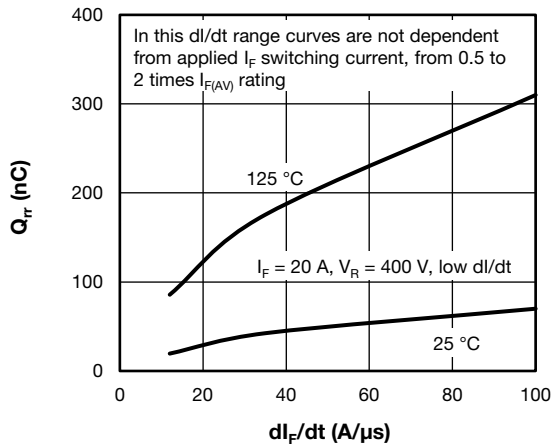


Fig. 11 - Typical Reverse Recovery Charge vs.  $di_F/dt$

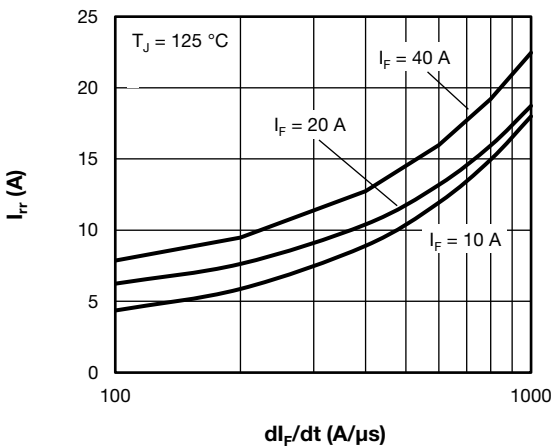


Fig. 9 - Typical Reverse Recovery Current vs.  $di_F/dt$

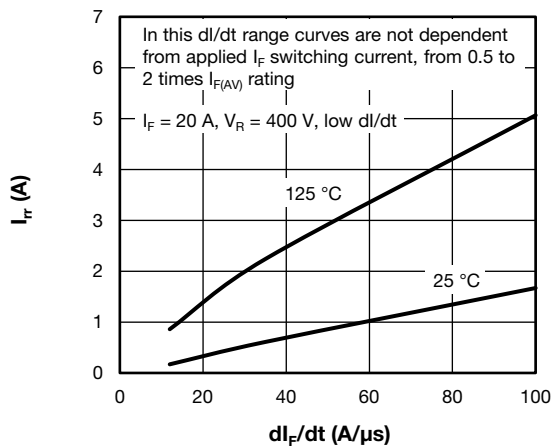


Fig. 12 - Typical Reverse Recovery Current vs.  $di_F/dt$

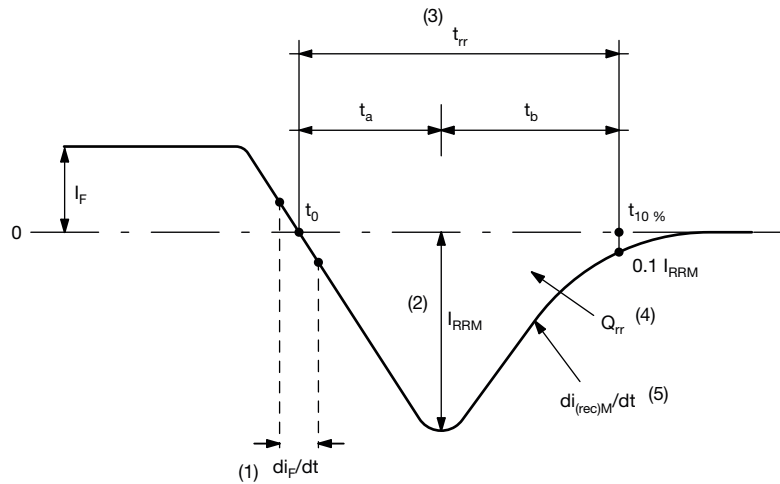


Fig. 13 - Reverse Recovery Waveform and Definitions

**Notes**

- (1)  $di_F/dt$  - rate of change of current through zero crossing
- (2)  $I_{RRM}$  - peak reverse recovery current
- (3)  $t_{rr}$  - reverse recovery time measured from  $t_0$ , crossing point of negative going  $I_F$ , to point  $t_{10\%}$ ,  $0.1 I_{RRM}$
- (4)  $Q_{rr}$  - area under curve defined by  $t_0$  and  $t_{10\%}$

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

- (5)  $di_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$



## ORDERING INFORMATION TABLE

Device code	<b>VS-</b>	<b>E</b>	<b>5</b>	<b>T</b>	<b>X</b>	<b>21</b>	<b>06</b>	<b>S2</b>	<b>L</b>	<b>H</b>	<b>M3</b>
	①	②	③	④	⑤	⑥	⑦	⑧	⑨	⑩	⑪

- 1** - Vishay Semiconductors product
- 2** - E = single diode
- 3** - 5 = FRED generation 5
- 4** - Package:  
T = D<sup>2</sup>PAK (TO-263) package
- 5** - X = hyperfast recovery
- 6** - Current rating (21 = 20 A)
- 7** - Voltage rating (06 = 600 V)
- 8** - S2 = true 2 pin D<sup>2</sup>PAK
- 9** - None = tube (50 pieces)
  - L = tape and reel (left oriented, for D<sup>2</sup>PAK package)
 If needed different orientation/packaging, please contact factory
- 10** - H = AEC-Q101 qualified
- 11** - Environmental digit:  
M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

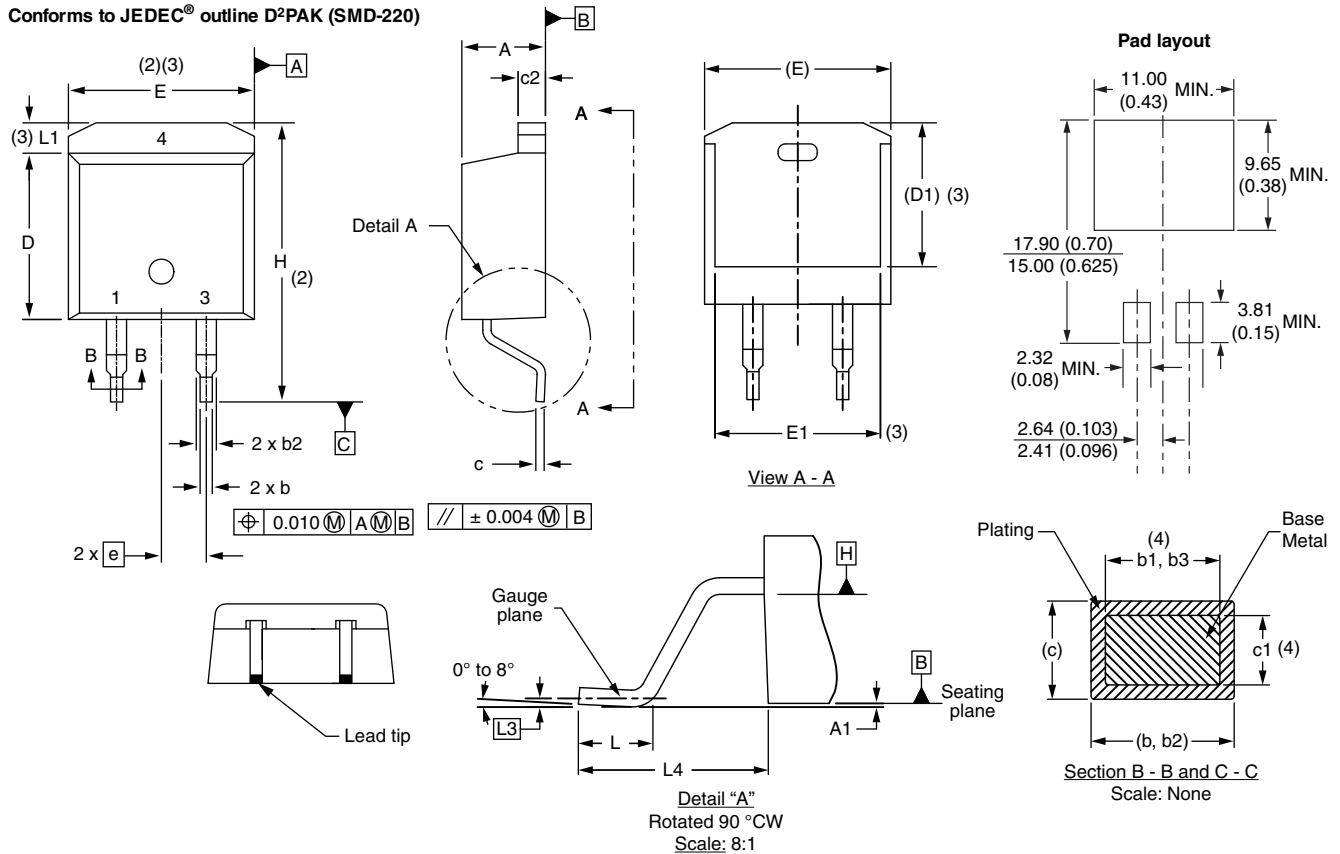
ORDERING INFORMATION (Example)		
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION
VS-E5TX2106S2LHM3	800	13" diameter reel

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?96683">www.vishay.com/doc?96683</a>
Part marking information	<a href="http://www.vishay.com/doc?96693">www.vishay.com/doc?96693</a>
Packaging information	<a href="http://www.vishay.com/doc?95032">www.vishay.com/doc?95032</a>

## D<sup>2</sup>PAK 2L (TO-263AB 2L)

### DIMENSIONS in millimeters and inches

Conforms to JEDEC<sup>®</sup> outline D<sup>2</sup>PAK (SMD-220)



SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.			MIN.	MAX.	MIN.	MAX.	
A	4.06	4.83	0.160	0.190		D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010		E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039		E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4	e	2.54 BSC		0.100 BSC		
b2	1.14	1.78	0.045	0.070		H	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4	L	1.78	2.79	0.070	0.110	
c	0.38	0.74	0.015	0.029		L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4	L3	0.25 BSC		0.010 BSC		
c2	1.14	1.65	0.045	0.065		L4	4.78	5.28	0.188	0.208	
D	8.51	9.65	0.335	0.380	2						

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC<sup>®</sup> outline TO-263AB



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